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Traces of stimulated bosonic exciton-scattering in sem iconductor lum inescence

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We observe signatures of stim ulated bosonic scattering of excitons, a precursor of Bose-E instein-Condensation (BEC), in the photolum inescence of sem iconductor quantum wells. The optical decay of a spinless molecule of two excitons (biexciton) into an exciton and a photon with opposite angular momenta is subject to bosonic enhancement in the presence of other excitons. In a spin polarized gas of excitons the bosonic enhancement breaks the symmetry of two equivalent decay channels leading to circularly polarized lum inescence of the biexciton with the sign opposite to the excitonic lum inescence. Comparison of experiment and many body theory proves stimulated scattering of excitons, but excludes the presence of a fully condensed BEC-like state.

In the last few decades intensive theoretical and experin entalwork has been devoted to the understanding and observation of a m acroscopic ground state of correlated electrons and holes in sem iconductor structures. A nalogous to Bose-Einstein-Condensation (BEC) of atom s, a dilute gas of bound electron-hole pairs - so called excitons - is predicted to condense into a common ground state [1, 2, 3]. Observation of condensation had been reported in CuO₂, where excitons with extraordinary long radiative lifetim e exhibit signatures of BEC [4]. M ore recently, the observation of a macroscopically ordered state in a G aA s based heterostructures was interpreted in term s of exciton condensation [5]. However, all reports on possible exciton condensation are controversially discussed and alternative interpretations of the experim ental data have been given [6, 7]. C lear criteria that are able to give unam biguous evidence for bosonic e ects and ultim ately BEC are therefore highly desirable. A precursor of excitonic BEC is stimulated scattering of excitons into other exciton states. The scattering rate is proportional to a bosonic enhancement factor (1 + n), where n is the num ber of excitons in the nalstate. In this letter we present experim ental evidence for stimulated bosonic scattering in the exciton system of optically excited sem iconductor quantum wells (QW s). The optical decay of a spinless biexciton (molecule of two excitons) into an exciton and a photon with opposite spin is subject to bosonic enhancem ent. The presence of spin polarized excitons causes the biexciton to decay preferentially into an exciton with the same spin. The resulting in balance of circularly polarized photons in the nalstate leaves as signature a nite degree of circular polarization at the biexciton photolum inescence (PL) line. We report on clear experimental evidence for the described e ect in sem iconductor QW s. A full quantum mechanical many body model yields a criterion for bosonic e ects which by comparison with our data proofs stimulated scattering but excludes the presence of a BEC-like state.

We investigate stimulated bosonic scattering in the photolum inescene of a high quality 10 nm thick ZnSe QW embedded in 500 nm $ZnS_{0:07}Se_{0:93}$ barriers grown by molecular beam epitaxy (MBE) on GaAs substrate

[8]. The sample is kept in a nger cryostat and excited with frequency doubled fs pulses from an 80 M H z T is apphire laser through a m icroscope objective to obtain high exciton densities. The spectral width of the pulses is narrowed down to below 4 meV by means of a pulse shaper to allow for resonant excitation of bound electrons and holes close to the exciton resonance which avoids the creation of hot carriers with excess energy. The polarization of the exciting light is carefully controlled by a Soleil-Babinet retarder. The sem iconductor lum inescence is measured in rejection geometry by a synchroscan streakcam era providing a spectral and tem poral resolution of 2 m eV and 6 ps, respectively. By passing the PL through an electrically tunable liquid-crystal retarder, the left and right circularly polarized components are separately measured without artifacts from possible beam displacement known from traditional optical elements like a =4-wave-plate.

W e optically excite excitons with angularm om entum $J_z = 1$ by pumping the sample with circularly polarized laser pulses of about 2 ps duration. Excitons with 1 are also created due to imperfect selection rules $J_z =$ and spin relaxation. Subsequently biexcitons are form ed by binding of excitons with opposite angularm om entum. Excitons with parallel angular momenta cannot form a bound state. The spin related criteria for binding are analogous to hydrogen where only atom swith antiparallel electron spin form molecules. Figure 1(b) depicts a PL spectrum 20 ps after excitation at a sam ple tem perature of 10 K. The high energy lum in escence peak results from the optical recombination of excitons. Because of the small photon m om entum only excitons with m om en-0 contribute to the emission. The low energy tum K lum inescence peak results from the decay of a biexciton into a photon and a free exciton. The energetic position $_{\rm bi}$, where E $_{\rm x}$ is the exciton enof the peak is at E_x ergy and bi is the biexciton binding energy. Because the biexciton consists of two excitons with opposite angular m om enta, one decay channel results in an em itted + polarized photon and a remaining $J_z =$ 1 exciton, whereas the other channel yields the opposite angular m om enta and $J_z = 1$). W ithin a four level scheme, the aver-(

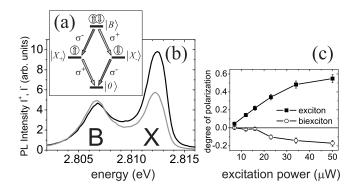


FIG.1: a) optical decay scheme, b) polarization resolved PL spectrum at T = 10 K, 20 ps after laser excitation. B lack line: ⁺ polarization. G ray line: polarization. c) density dependence of polarization 15 ps after excitation, exciton (full squares) and biexciton (open circles).

age optical em ission of biexcitons should be completely unpolarized [Fig. 1(a)].

In contrast, we nd for high excitation densities circular polarized em ission at the biexciton line, whose sign is opposite to that of the excitons. Figure 1 (b) shows the circular polarized PL spectrum 20 ps after quasi resonant excitation of the exciton resonance with 50 W creating an estimated exciton density of about 8 10^{11} cm 2 . The time delay quarantees that the initial coherence of laser pulse and excitons has completely vanished. The spectrum clearly shows the polarization e ect. The magnitude of biexciton polarization increases with increasing exciton density from zero to about 17 % [Fig. 1 (c)]. The simultaneous increase of polarization at the exciton can be explained by the increasing fraction of excitons with opposite spin that are bound into biexcitons and therefore do not contribute to excitonic emission with opposite circular polarization. For low densities, the degree of exciton polarization is much lower than expected from the selection rules. We explain this by a short electron spin relaxation time s which decreases from about 100 ps to 20 ps at lowest densities [9]. Independently, we observed the same biexciton polarization e ect also in 5 nm ZnSe/ZnMgSSemultipleQW s and in a 9.9 nm G = A s / A = s single Q W.

In the follow ing we exclude a num ber of artifacts that m ight have caused the polarized em ission at the biexciton line. (i) C reating excitons with opposite circular polarized laser pulses changes both, the sign of exciton and biexciton photolum inescence. This exclude that the biexciton polarization is caused by some polarizing element in the optical path of the lum inescence or by some a sym metry which could have favored negative polarization. Sim ilarly, the application of an in-plane magnetic eld leads to spin-oscillations which modulate both the exciton and biexciton polarization with the same frequency [10]. (ii) The optical dielectric function of a QW is after excitation with circular polarized light no longer the same

for + and polarized light. Since the rate of spontaneous em ission depends on refractive index and reabsorption, we calculated em ission at the biexcitonic line taking into account the polarization dependent dielectric function and the dielectric properties of the sample structure [11]. We found a low degree of polarization induced by the spin dependent sam ple properties, that, how ever, exhibited the same sign as the exciton polarization. I.e., the surprising polarization e ect of the biexciton m ay be even larger than it appears from the bare lum inescence data. (iii) A large energetic spin splitting of the exciton levels induced by exchange interaction would lead to energetically distinct fully polarized biexciton lines with equal intensity, but no average polarization. A nite splitting could therefore explain polarized em ission in the low energy tail of the biexciton line. This artifact is excluded, because, rst, there is no visible splitting of the exciton lines, and, second, integration over the full biexciton line still exhibits polarized em ission.

We will rst give a prelim inary explanation of polarized emission at the biexciton line based on the Dicke theory of spontaneous emission, which originally was developed to treat cooperative optical decay of several multi-level atom s in a sm all volum e [12, 13, 14]. Consider a chain of N adjacent sites which can be occupied by an exciton with either spin 1, spin -1, or a biexciton [15]. The chain may be viewed as a quantum wire with the length of N exciton units and periodic boundary conditions. In this picture the decay of an exciton at a certain site corresponds to the transition from an excited atom ic level X_{i} ; i to the ground state \mathcal{D}_i i. The PL intensity of the full exciton chain at the exciton line is given by $I = hR^{y}R$ i, where $R = \prod_{i=1}^{P} \mathcal{D}_{i} \text{ in } X_{i}; \text{ jis the macroscopic dipole operator}$ of all N excitons and i labels the exciton sites. Photon em ission at the biexciton line is linked to the annihilation of a biexciton, X $_{j_{i^+}}$ X $_{j_i}$, and the creation of an exciton, X $\frac{Y}{1:+}$, and a photon with opposite angularm om entum . W ithin the D icke form alism one needs to calculate I_{b} ; = $hR_{b,p}^{\gamma}R_{b}$; i, where the macroscopic dipole operator R_{b} ; = $\sum_{j=1}^{l} X_{j}^{y}$; $X_{j+}X_{j}$; is now expressed in second quantization with the operator relations X $_{i}$; X $_{j}$; = X_{j} ; X_{i} ; and $X_{i}^{2} = 0$ (hard core bosons). Exciton and biexciton operators can be de ned in momentum space x_k ; = N $\sum_{j=1}^{l=2} X_j$; exp (2 ik j=N), $_{j=1}^{1=2} \sum_{j=1}^{N} X_{j+} X_{j}$; exp (2 ik j=N) with k = $b_k = N$ 0;:::; (N 1)=2, which is closer to the usual notation in sem iconductor theory. In this representation we nd $k_{k}^{k_{0}}hb_{k}^{y}x_{k}; x_{k}^{y}; b_{k}^{o}i,$ for biexciton lum in escence I_{b} ; = im plying m om entum conservation as expected. For calculating PL of a sample with incoherent excitons and biexcitons we can drop o -diagonal term s with $k \in k^0$. W e proceed calculating the k-dependent term s I_k ; = $hb_k^y x_k$; x_k^y : b_k i by applying the exact B ose-commutation

relations x_k ; x_{k}^y ; $x_{k,p}^y$; $x_{k,p}^y$; x_k ; = 1 2n =N, where the number operator n = $_k x_{k}^y$; x_k ; counts all excitons with the same spin (including excitons bound in biexcitons). A fler approximating the four operator expectation values by factorized products, the biexciton PL intensity obtains the nal form

$$I_{k}; = hb_{k}^{y}(1 + x_{k}^{y}; x_{k}; 2n = N)b_{k}i$$

$$h_{k}^{y}b_{k}i + hx_{k}^{y}; x_{k}; i - 2\frac{hn i}{N} : (1)$$

It follows that biexciton emission I_k ; depends not only on the occupation of biexcitons $h_{t}^{y}b_{k}i$ but also on a enhancement factor $1 + hx_{k}^{Y} x_{k}$; i 2hn i=N . We interpret this factor as stimulated bosonic scattering of nal state excitons with momentum k into excitons that were already present in the state k. This immediately explains the negative circular polarized biexciton PL in the presence of spin polarized excitons with positive angular m om enta $hx_{k;+}^{y} x_{k;+} i > hx_{k;}^{y} x_{k;}$ i. Sim ilarly, positive circular polarization is observed in the presence of excitons with negative angularm om enta. Only for highest exciton densities [m i=N 50%] the third term of the enhancement factor may dominate and lead in special cases to polarized biexciton em ission with the same sign as the excitons. Our observations exhibit a clear deviation of the usual proportionality between occupation number and PL intensity in sem iconductors (without a laser-like optical feedback).

The derivation above already gives a good in pression of the origin of the polarization e ect. However, the calculation does not regard exciton energy dispersion, and makes no prediction about the actual exciton-biexciton distribution which at high densities is not simply described by a Bose-E instein distribution. Excitons are no ideal bosons and the Pauli exclusion principle applies to their ferm ionic constituents, electrons and holes. Inclusion of such features is unfortunately beyond the applicability of full m icroscopic theories of sem iconductor lum inescence that neglect spin and correlations related to biexcitons [16, 17, 18, 19]. We therefore introduce a simpli ed model Ham iltonian for a 1D exciton biexciton system

$$H = \begin{matrix} X & & X \\ & E_{k} x_{k}^{y}, x_{k}, \end{matrix} \qquad \qquad b X_{j+}^{y} X_{j+} X_{j}^{y}, X_{j}, ; (2)$$

$$K_{k} = j$$

that quantitatively includes the exciton dispersion E_k . B iexciton formation is included by a short range (onsite) potential well with depth $_b$, which in principle allows for a biexciton state that extends in contrast to the D icke m odel over m ore than just one site. The distance between two adjacent sites is assumed to be four exciton B ohr radii 4a₀, which correspond to kinetic exciton m omenta of $p_k = hk=2a_0N$ [20]. We obtain with the experimental values for exciton radius $a_0 = 5$ nm and

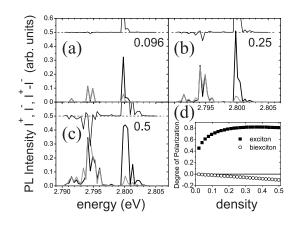


FIG. 2: a)-c) Calculated polarized PL spectra I^+ , I, and I^+ I (o set by 0.5 for better visibility) at T = 15 K for increasing densities of 0.096, 0.25, and 0.5 excitons per site. d) density dependence of the excitonic and biexcitonic degree of polarization.

the exciton mass m_X = $0.344m_0$ the exciton dispersion relation $E_k = E_X + p_k^2 = 2m_X$ with a maximum kinetic energy of about $E_{max} = 11 \text{ meV}$ and $E_X = 2.8 \text{ eV}$. In order to calculate the lum inescence spectrum of the system at a given temperature, we calculate the multi particle density matrix

$$/ \exp \frac{1}{k_{\rm B} T} (H_{+} n_{+} n_{-})$$
 (3)

where $_{+}$ and are the chem ical potentials which govem the average number of spin up h_{+} i and spin down hn i excitons. The intensity of polarized PL em itted by decay of a multi-particle energy eigenstate $j_{i}i$ into a state $j_{f}i$ is given by $I_{i,f} = f_{f} f_{f} j_{i}i j_{i}^{2}$; where $D = d X_{j}$; is the overall dipole operator (in rotating wave approximation). Consequently, the full polarized lum inescence spectrum that belongs to the mixed state is given by

gweir.

$$I() = \begin{array}{c} X \\ h_{i}jj_{i}j_{f} f j j_{i}i_{f} f j j_{i}i_{f} f j ((i f)); \\ i_{f}f \end{cases}$$
(4)

where has the hom ogenous linew idth of an optical em ission event and i is the energy of the multi-exciton states. Figure 2 shows the calculated PL spectra for + and polarization for the model with N = 5 sites $(2^{2})^{5}$ 2 5 density matrix) at a temperature of T = 15 K and with a xed spin polarization $(m^+i m i) = (m^+i + m i) =$ 0:25. At low densities hx_{k}^{y} , x_{k} ; i 1 there is alm ost no biexciton polarization e ect as expected [com pare eq. (1)]. At elevated densities, the polarization e ect increases signi cantly to up to 10 % at a density of 0:5 excitons per site (2.5 excitons distribute over all 5 sites), which corresponds to about $1:25 \quad 10^{12}$ cm². The calculated m agnitude of the biexciton polarization e ect in the di erent density regim es com pares qualitatively well

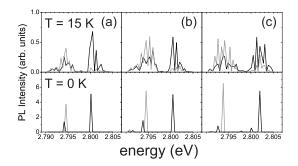


FIG.3: Calculated PL spectra at T = 15 and T = 0 K.a) Number of excitons (n₊, n) = (2,1) b) (3,2) c) (4,2).

with experiment. Also the relative height of exciton and biexciton peak compares well with our measurement. We obtain improved agreement with data if we assume an exciton temperature of T = 30 K in the calculations, which can be understood by the increase of carrier temperature during the binding process of biexcitons.

N ext we discuss criteria to observe BEC-like condensation in the exciton biexciton system. First we show that the calculated ground state of ourm odelH am ilton can be well approxim ated by an analytical expression which has the from of a phase average BCS-like state (BCS state becomes a BEC state in the low density lim it)

$$j (_{1};_{2})i / \underset{i=1}{\overset{N}{\longrightarrow}} 1 + c_{1}e^{i_{1}}X_{i;+}^{y} + c_{2}e^{i_{2}}X_{i;+}^{y}X_{i;}^{y} \quad jDi;$$
(5)

which contains excitons and biexcitons as condensing entities with two macroscopic phases $_1$ and $_2$. Since the Ham ilton H commutes with the particle operators n, the ground state is required to posses sharp particle num – bers which we obtain by phase-averaging j ($_1$; $_2$)i

$$z_2$$

j (n;m)i/ j (1; 2)ie ^{i(n m)} ^{im} ²d_1d_2; (6)
_{1; 2}=0

where n and m are the number of excitons with spin 1 and spin 1, respectively. The overlap h (m;n)j (m;n)ij² of the BCS-like state with the numerically gained ground states j (m;n)i exhibits good agreem ent (ranging from 0.6 and 1.0). The calculated em ission spectra for j (m;n) i w ith n > m revealat T = 0sharp peaks at the exciton and biexciton energy [g. 3, bottom row]. The biexciton peak shows a high degree of polarization which increases with density. The presence of strongly polarized biexciton em ission is a clear signature for a highly correlated multi exciton state. The exciton peak is 100 % polarized, because allm inority excitons with opposite spin form a biexciton at zero tem perature. For comparison, a system with the same average exciton densities, but T = 15 K exhibits broad spectral features and a much lower degree of polarization at the biexciton and exciton resonance [g. 3, top row]. Consequently, we

suggest as a criterion for a condensed system of partially polarized exciton the observation of sharp PL lines with a high degree of polarization at the exciton and biexciton emission PL line. This criterion is experimentally less demanding than the suggested measurement of the photon statistics of emitted light [18, 19]. Applying the criterion to our data, we conclude that we observe stim – ulated bosonic scattering of excitons, but do not observe a fully condensed multi-exciton state.

In conclusion we found unambiguous traces of stim ulated bosonic scattering of excitons in the photolum inescence of a photo-generated exciton biexciton system. The spectral signature at the biexciton line is explained in terms of cooperatively radiating excitons and biexcitons within D icke theory and num erically treated within a m any body theory which yields all m a pr features of our experim ental observations.

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ing corresponds to a broader potential well for biexciton binding and a lower maximum density of excitons that can be described in our model.